



74HC4316; 74HCT4316

Quad single-pole single-throw analog switch

Rev. 7 — 26 March 2024

Product data sheet

1. General description

The 74HC4316; 74HCT4316 is a quad single pole, single throw analog switch (SPST). Each switch features two input/output terminals (nY and nZ) and an active HIGH enable input (nS). When nS is LOW, the analog switch is turned off. When E is HIGH all four analog switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

2. Features and benefits

- CMOS low power dissipation
- High noise immunity
- Input levels E and nS inputs:
 - For 74HC4316: CMOS level
 - For 74HCT4316: TTL level
- Low ON resistance:
 - 160 Ω (typical) at $V_{CC} - V_{EE} = 4.5$ V
 - 120 Ω (typical) at $V_{CC} - V_{EE} = 6.0$ V
 - 80 Ω (typical) at $V_{CC} - V_{EE} = 9.0$ V
- Logic level translation:
 - To enable 5 V logic to communicate with ± 5 V analog signals
- Typical break-before-make built in
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- Signal gating
- Modulation
- Demodulation
- Chopper

4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC4316D 74HCT4316D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC4316PW 74HCT4316PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

5. Functional diagram

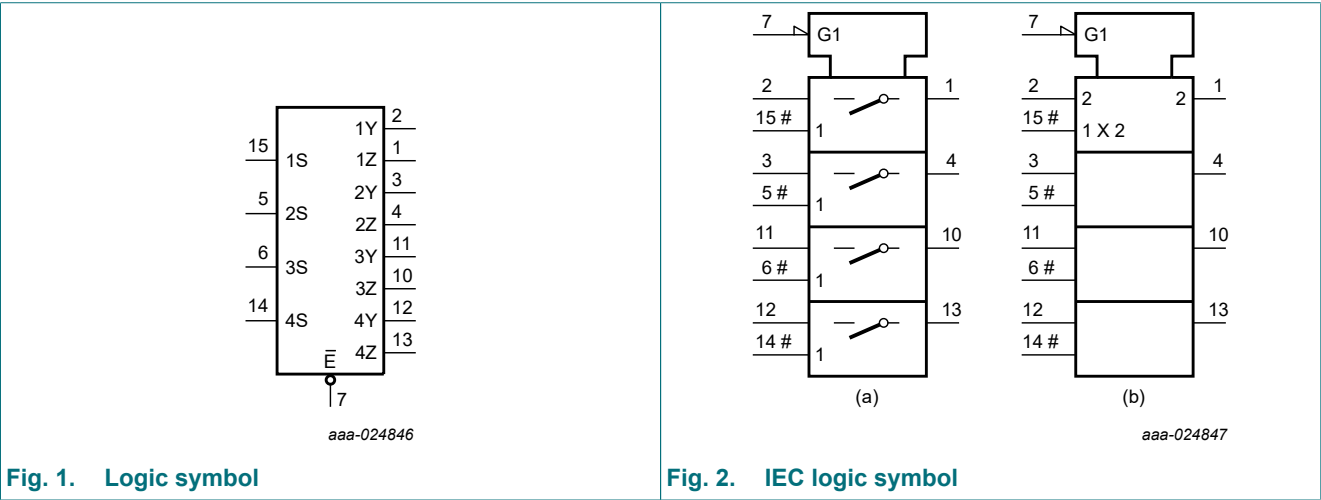


Fig. 1. Logic symbol

Fig. 2. IEC logic symbol

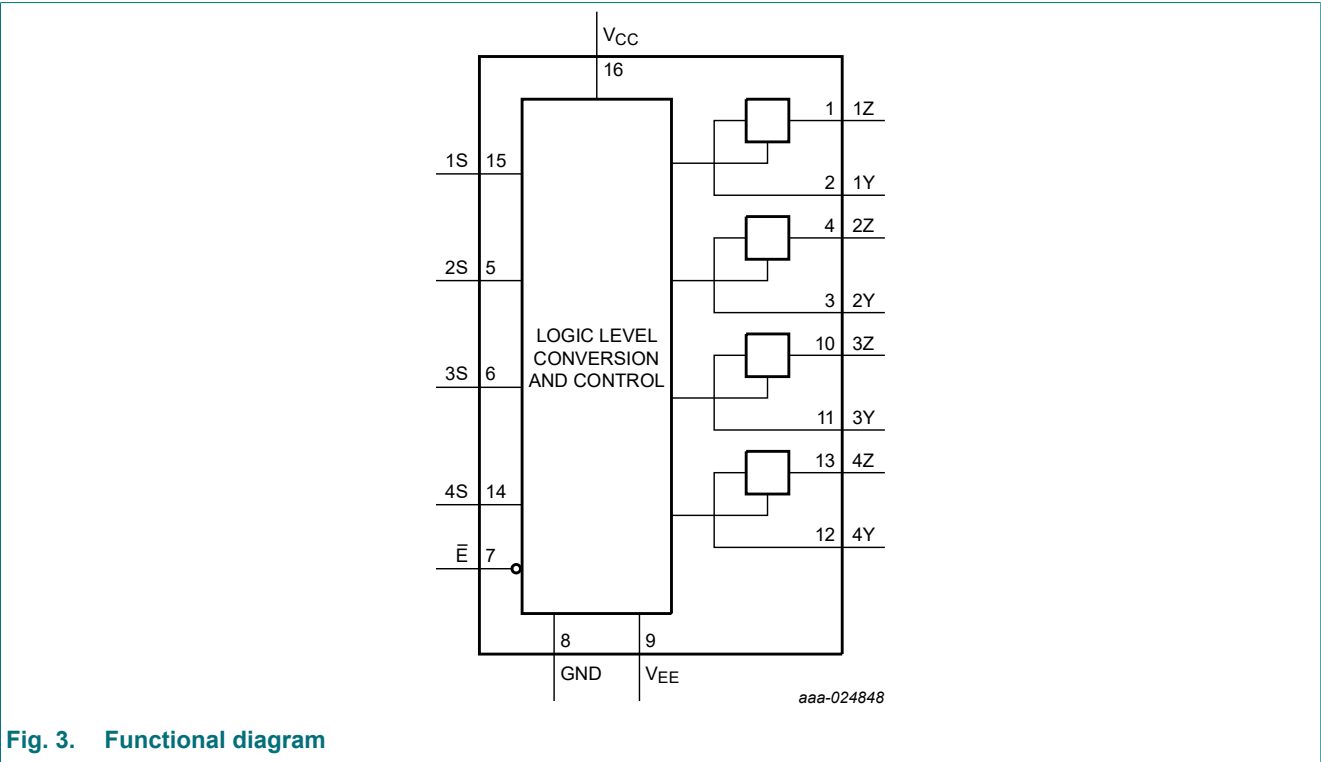


Fig. 3. Functional diagram

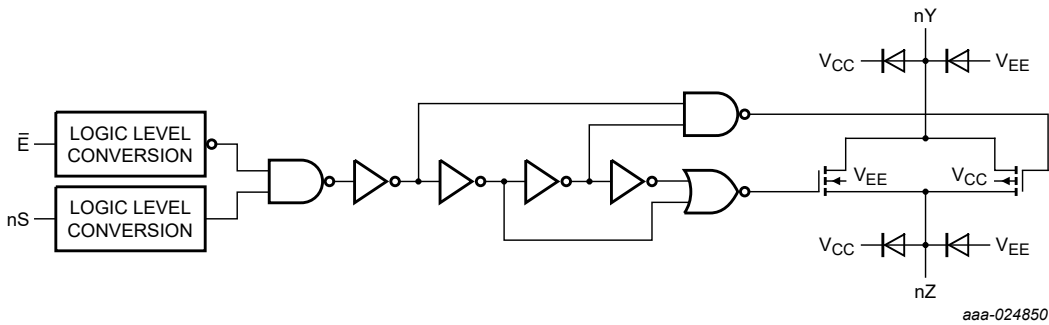
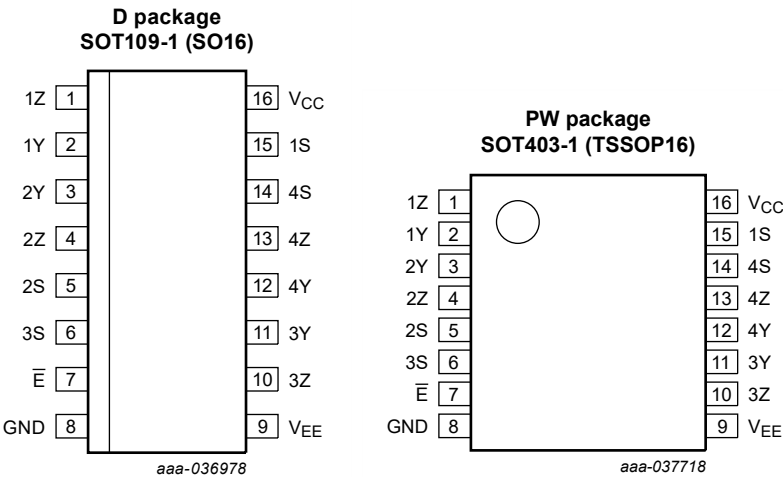


Fig. 4. Schematic diagram (one switch)

6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1Z, 2Z, 3Z, 4Z	1, 4, 10, 13	independent input or output
1Y, 2Y, 3Y, 4Y	2, 3, 11, 12	independent input or output
$\bar{E}$	7	enable input (active LOW)
GND	8	ground (0 V)
V_{EE}	9	negative supply voltage
1S, 2S, 3S, 4S	15, 5, 6, 14	select input (active HIGH)
V_{CC}	14	positive supply voltage

7. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Input		Switch
E	nS	
L	L	OFF
L	H	ON
H	X	OFF

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+11.0	V
I _{IK}	input clamping current	V _I < -0.5 V or V _I > V _{CC} + 0.5 V	-	±20	mA
I _{SK}	switch clamping current	V _{SW} < -0.5 V or V _{SW} > V _{CC} + 0.5 V	-	±20	mA
I _{SW}	switch current	V _{SW} = -0.5 V to V _{CC} + 0.5 V [1]	-	±25	mA
I _{EE}	supply current		-	20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C [2]	-	500	mW
P	power dissipation	per switch	-	100	mW

- [1] To avoid drawing V_{CC} current out of terminal nZ, when switch current flows in terminals nY, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no V_{CC} current will flow out of terminals nY. In this case there is no limit for the voltage drop across the switch, but the voltages at nY and nZ may not exceed V_{CC} or V_{EE}.
- [2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.
For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74HC4316			74HCT4316			Unit
			Min	Typ	Max	Min	Typ	Max	
V _{CC}	supply voltage	see Fig. 5 and Fig. 6							
		V _{CC} - GND	2.0	5.0	10.0	4.5	5.0	5.5	V
		V _{EE} - GND	2.0	5.0	10.0	2.0	5.0	10.0	V
V _I	input voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
V _{SW}	switch voltage		V _{EE}	-	V _{CC}	V _{EE}	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V
		V _{CC} = 10.0 V	-	-	35	-	-	-	ns/V

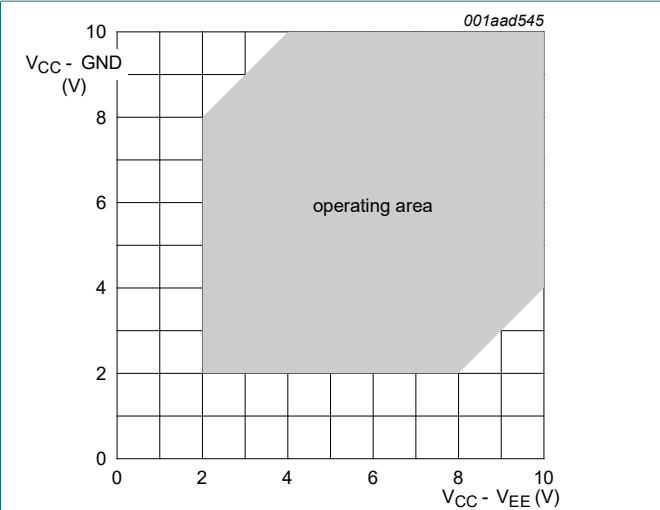


Fig. 5. Guaranteed operating area as a function of the supply voltages for 74HC4316

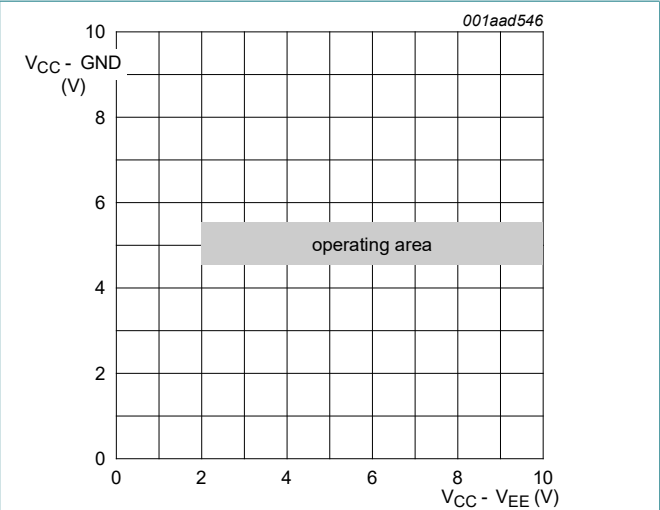


Fig. 6. Guaranteed operating area as a function of the supply voltages for 74HCT4316

10. Static characteristics

Table 6. R_{ON} resistance per switch for types 74HC4316 and 74HCT4316

$V_I = V_{IH}$ or V_{IL} ; for test circuit see Fig. 7.
 V_{is} is the input voltage at a nY or nZ terminal, whichever is assigned as an input.
 V_{os} is the output voltage at a nY or nZ terminal, whichever is assigned as an output.
For 74HC4316: $V_{CC} - GND$ or $V_{CC} - V_{EE} = 2.0\text{ V}$, 4.5 V , 6.0 V and 9.0 V .
For 74HCT4316: $V_{CC} - GND = 4.5\text{ V}$ and 5.5 V ; $V_{CC} - V_{EE} = 2.0\text{ V}$, 4.5 V , 6.0 V and 9.0 V .

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Typ	Max	Min	Max	Min	Max	
$R_{ON(peak)}$	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE} [1]							
		$V_{CC} = 2.0\text{ V}$; $V_{EE} = 0\text{ V}$; $I_{SW} = 100\text{ }\mu\text{A}$	-	-	-	-	-	-	Ω
		$V_{CC} = 4.5\text{ V}$; $V_{EE} = 0\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	160	320	-	400	-	480	Ω
		$V_{CC} = 6.0\text{ V}$; $V_{EE} = 0\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	120	240	-	300	-	360	Ω
		$V_{CC} = 4.5\text{ V}$; $V_{EE} = -4.5\text{ V}$; $I_{SW} = 1000\text{ }\mu\text{A}$	85	170	-	215	-	255	Ω

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Typ	Max	Min	Max	Min	Max	
R _{ON(rail)}	ON resistance (rail)	V _{is} = V _{EE} [1]							
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 µA	160	-	-	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 µA	80	160	-	200	-	240	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 µA	70	140	-	175	-	210	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 µA	60	120	-	150	-	180	Ω
		V _{is} = V _{CC} [1]							
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 µA	170	-	-	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 µA	90	180	-	225	-	270	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 µA	80	160	-	200	-	240	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 µA	65	135	-	170	-	205	Ω
ΔR _{ON}	ON resistance mismatch between channels	V _{is} = V _{CC} to V _{EE} [1]							
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	-	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V	16	-	-	-	-	-	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V	9	-	-	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	6	-	-	-	-	-	Ω

[1] When supply voltages (V_{CC} - V_{EE}) near 2.0 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 2 V, it is recommended to use these devices only for transmitting digital signals.

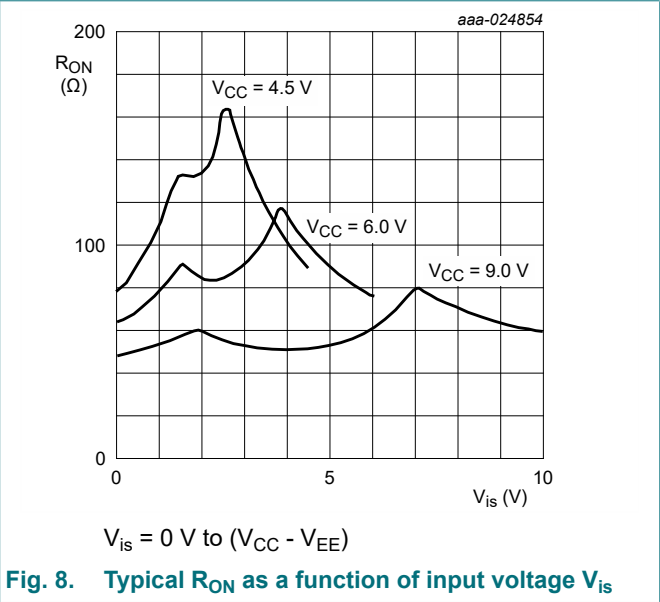
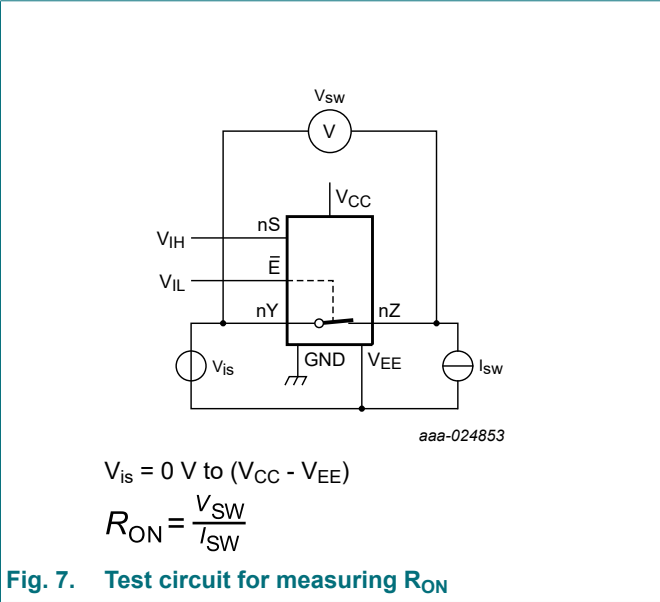


Table 7. Static characteristics 74HC4316

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

V_{IS} is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

V_{OS} is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.3	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
		V _{CC} = 9.0 V	-	4.3	2.7	V
I _I	input leakage current	V _I = V _{CC} or GND				
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	±0.1	µA
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	±0.2	µA
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 10.0 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 9	-	-	±0.1	µA
I _{S(ON)}	ON-state leakage current	V _{CC} = 10.0 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 10	-	-	±0.1	µA
I _{CC}	supply current	V _I = V _{CC} or GND; V _{IS} = V _{EE} or V _{CC} ; V _{OS} = V _{CC} or V _{EE}				
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	8.0	µA
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	16.0	µA
C _I	input capacitance		-	3.5	-	pF
C _{SW}	switch capacitance		-	5	-	pF
T_{amb} = -40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
I _I	input leakage current	V _I = V _{CC} or GND				
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	±1.0	µA
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	±2.0	µA
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 10.0 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 9	-	-	±1.0	µA
I _{S(ON)}	ON-state leakage current	V _{CC} = 10.0 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 10	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; V _{IS} = V _{EE} or V _{CC} ; V _{OS} = V _{CC} or V _{EE}				
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	80.0	µA
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	160.0	µA

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = -40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
I _I	input leakage current	V _I = V _{CC} or GND				
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	±1.0	µA
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	±2.0	µA
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 10.0 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 9	-	-	±1.0	µA
I _{S(ON)}	ON-state leakage current	V _{CC} = 10.0 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 10	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; V _{is} = V _{EE} or V _{CC} ; V _{os} = V _{CC} or V _{EE}				
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	160	µA
		V _{CC} = 10.0 V; V _{EE} = 0 V	-	-	320	µA

Table 8. Static characteristics 74HCT4316

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).
V_{is} is the input voltage at a nY or nZ terminal, whichever is assigned as an input.
V_{os} is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	±0.1	µA
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 10 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 9	-	-	±0.1	µA
I _{S(ON)}	ON-state leakage current	V _{CC} = 10 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 10	-	-	±0.1	µA
I _{CC}	supply current	V _I = V _{CC} or GND; V _{is} = V _{EE} or V _{CC} ; V _{os} = V _{CC} or V _{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	8.0	µA
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	16.0	µA
ΔI _{CC}	additional supply current	nS and $\bar{E}$; per input pin; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V; V _{EE} = 0 V	-	50	180	µA
C _I	input capacitance		-	3.5	-	pF
C _{SW}	switch capacitance		-	5	-	pF

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = -40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	±1.0	µA
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 10 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 9	-	-	±1.0	µA
I _{S(ON)}	ON-state leakage current	V _{CC} = 10 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 10	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; V _{is} = V _{EE} or V _{CC} ; V _{os} = V _{CC} or V _{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	80	µA
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	160	µA
ΔI _{CC}	additional supply current	nS and $\bar{E}$; per input pin; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V; V _{EE} = 0 V	-	-	225	µA
T_{amb} = -40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
I _I	input leakage current	V _I = V _{CC} or GND; V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	±1.0	µA
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 10 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 9	-	-	±1.0	µA
I _{S(ON)}	ON-state leakage current	V _{CC} = 10 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see Fig. 10	-	-	±1.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; V _{is} = V _{EE} or V _{CC} ; V _{os} = V _{CC} or V _{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	160	µA
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	320	µA
ΔI _{CC}	additional supply current	nS and $\bar{E}$; per input pin; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V; V _{EE} = 0 V	-	-	245	µA

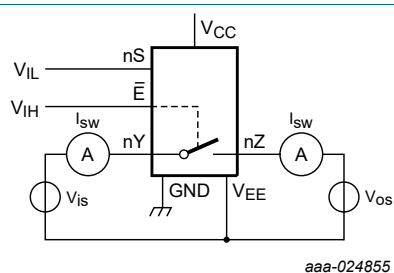


Fig. 9. Test circuit for measuring OFF-state leakage current

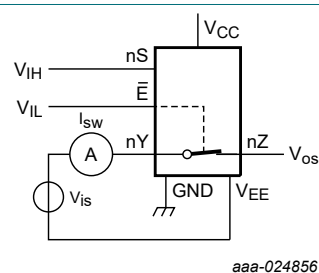


Fig. 10. Test circuit for measuring ON-state leakage current

11. Dynamic characteristics

Table 9. Dynamic characteristics

$GND = 0\text{ V}$; $t_r = t_f = 6\text{ ns}$; $C_L = 50\text{ pF}$ unless specified otherwise; for test circuit see [Fig. 13](#).

V_{is} is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

V_{os} is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Typ	Max	Min	Max	Min	Max	
74HC4316									
t _{pd}	propagation delay	nY to nZ or nZ to nY; R _L = ∞ Ω; see Fig. 11 [1]							
		V _{CC} = 2.0 V; V _{EE} = 0 V	17	60	-	75	-	90	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	6	12	-	15	-	18	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	5	10	-	13	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	4	8	-	10	-	12	ns
t _{off}	turn-off time	$\bar{E}$ to nY or nZ; see Fig. 12 [2]							
		V _{CC} = 2.0 V; V _{EE} = 0 V	63	220	-	275	-	330	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	23	44	-	55	-	66	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	20	-	-	-	-	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	18	37	-	47	-	56	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	21	39	-	49	-	59	ns
		nS to nY or nZ; see Fig. 12 [2]							
		V _{CC} = 2.0 V; V _{EE} = 0 V	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	20	35	-	44	-	53	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	16	-	-	-	-	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	16	30	-	37	-	45	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	18	36	-	45	-	54	ns
		t _{on}	turn-on time	$\bar{E}$ to nY or nZ; see Fig. 12 [3]					
V _{CC} = 2.0 V; V _{EE} = 0 V	61			205	-	255	-	310	ns
V _{CC} = 4.5 V; V _{EE} = 0 V	22			41	-	51	-	62	ns
V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	19			-	-	-	-	-	ns
V _{CC} = 6.0 V; V _{EE} = 0 V	18			35	-	43	-	53	ns
V _{CC} = 4.5 V; V _{EE} = -4.5 V	19			37	-	47	-	56	ns
nS to nY or nZ; see Fig. 12 [3]									
V _{CC} = 2.0 V; V _{EE} = 0 V	52			175	-	220	-	265	ns
V _{CC} = 4.5 V; V _{EE} = 0 V	19			35	-	44	-	53	ns
V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	16			-	-	-	-	-	ns
V _{CC} = 6.0 V; V _{EE} = 0 V	15			30	-	37	-	45	ns
V _{CC} = 4.5 V; V _{EE} = -4.5 V	17			34	-	43	-	51	ns
C _{PD}	power dissipation capacitance			per switch; V _I = GND to V _{CC} [4]	13	-	-	-	-

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Typ	Max	Min	Max	Min	Max	
74HCT4316									
t _{pd}	propagation delay	nY to nZ or nZ to nY; R _L = ∞ Ω; see Fig. 11 [1]							
		V _{CC} = 4.5 V; V _{EE} = 0 V	6	12	-	15	-	18	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	4	8	-	10	-	12	ns
t _{pZH}	OFF-state to HIGH propagation delay	$\bar{E}$ to nY or nZ; see Fig. 12							
		V _{CC} = 4.5 V; V _{EE} = 0 V	22	44	-	55	-	66	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	19	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	21	42	-	53	-	63	ns
		nS to nY or nZ; see Fig. 12							
		V _{CC} = 4.5 V; V _{EE} = 0 V	20	40	-	53	-	60	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	17	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	17	34	-	43	-	51	ns
t _{pZL}	OFF-state to LOW propagation delay	$\bar{E}$ to nY or nZ; see Fig. 12							
		V _{CC} = 4.5 V; V _{EE} = 0 V	28	56	-	70	-	84	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	24	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	21	42	-	53	-	63	ns
		nS to nY or nZ; see Fig. 12							
		V _{CC} = 4.5 V; V _{EE} = 0 V	25	50	-	63	-	75	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	21	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	17	34	-	43	-	51	ns
t _{off}	turn-off time	$\bar{E}$ to nY or nZ; see Fig. 12 [2]							
		V _{CC} = 4.5 V; V _{EE} = 0 V	25	50	-	63	-	75	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	21	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	23	46	-	58	-	69	ns
		nS to nY or nZ; see Fig. 12 [2]							
		V _{CC} = 4.5 V; V _{EE} = 0 V	22	44	-	55	-	66	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	19	-	-	-	-	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	20	40	-	50	-	60	ns
C _{PD}	power dissipation capacitance	per switch; V _I = GND to (V _{CC} - 1.5 V) [4]	14	-	-	-	-	-	pF

[1] t_{pd} is the same as t_{pHL} and t_{PLH}.

[2] t_{off} is the same as t_{pZH} and t_{pZL}.

[3] t_{on} is the same as t_{pZH} and t_{pZL}.

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum((C_L + C_{sw}) \times V_{CC}^2 \times f_o)$ where:
f_i = input frequency in MHz;
f_o = output frequency in MHz;
 $\sum((C_L + C_{sw}) \times V_{CC}^2 \times f_o)$ = sum of outputs;
C_L = output load capacitance in pF;
C_{sw} = switch capacitance in pF;
V_{CC} = supply voltage in V.

11.1. Waveforms and test circuit

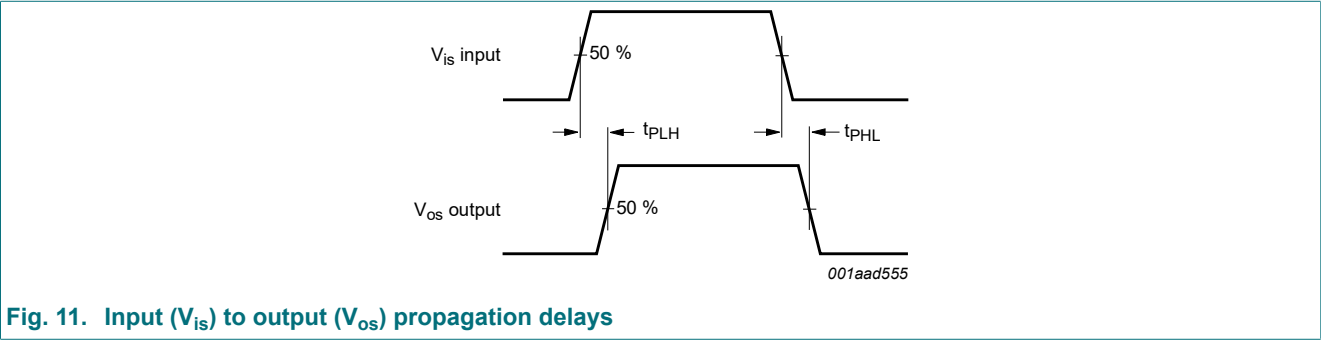


Fig. 11. Input (V_{is}) to output (V_{os}) propagation delays

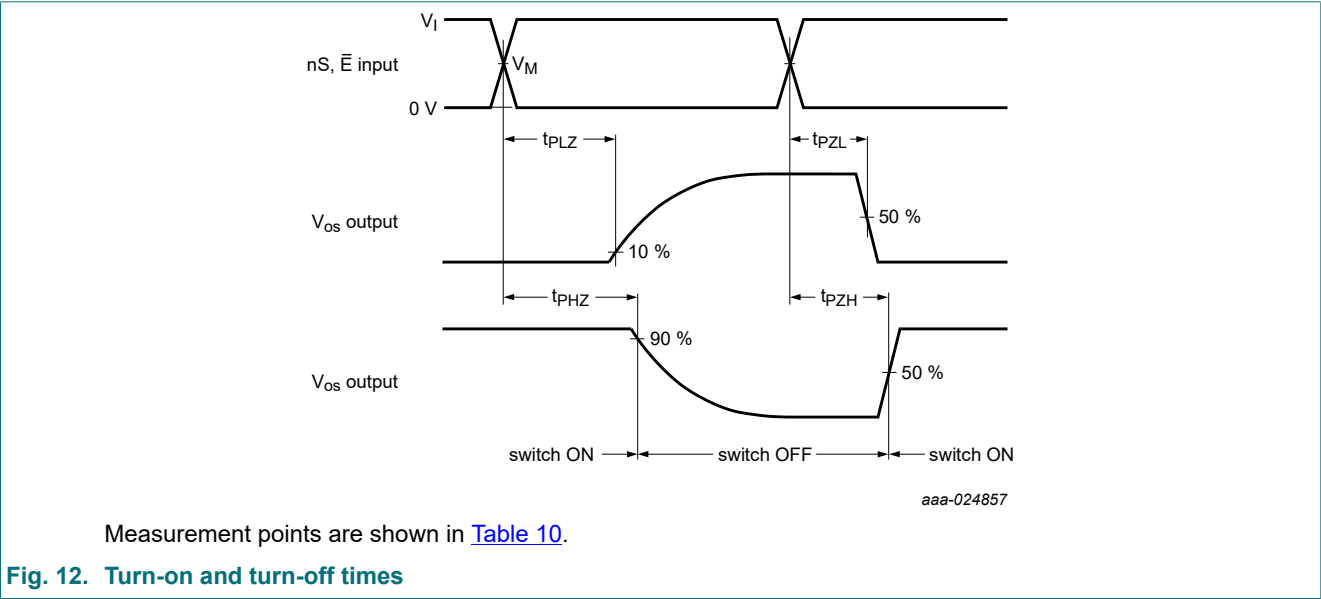


Fig. 12. Turn-on and turn-off times

Table 10. Measurement points

Type	V_I	V_M
74HC4316	V_{CC}	$0.5V_{CC}$
74HCT4316	3.0 V	1.3 V

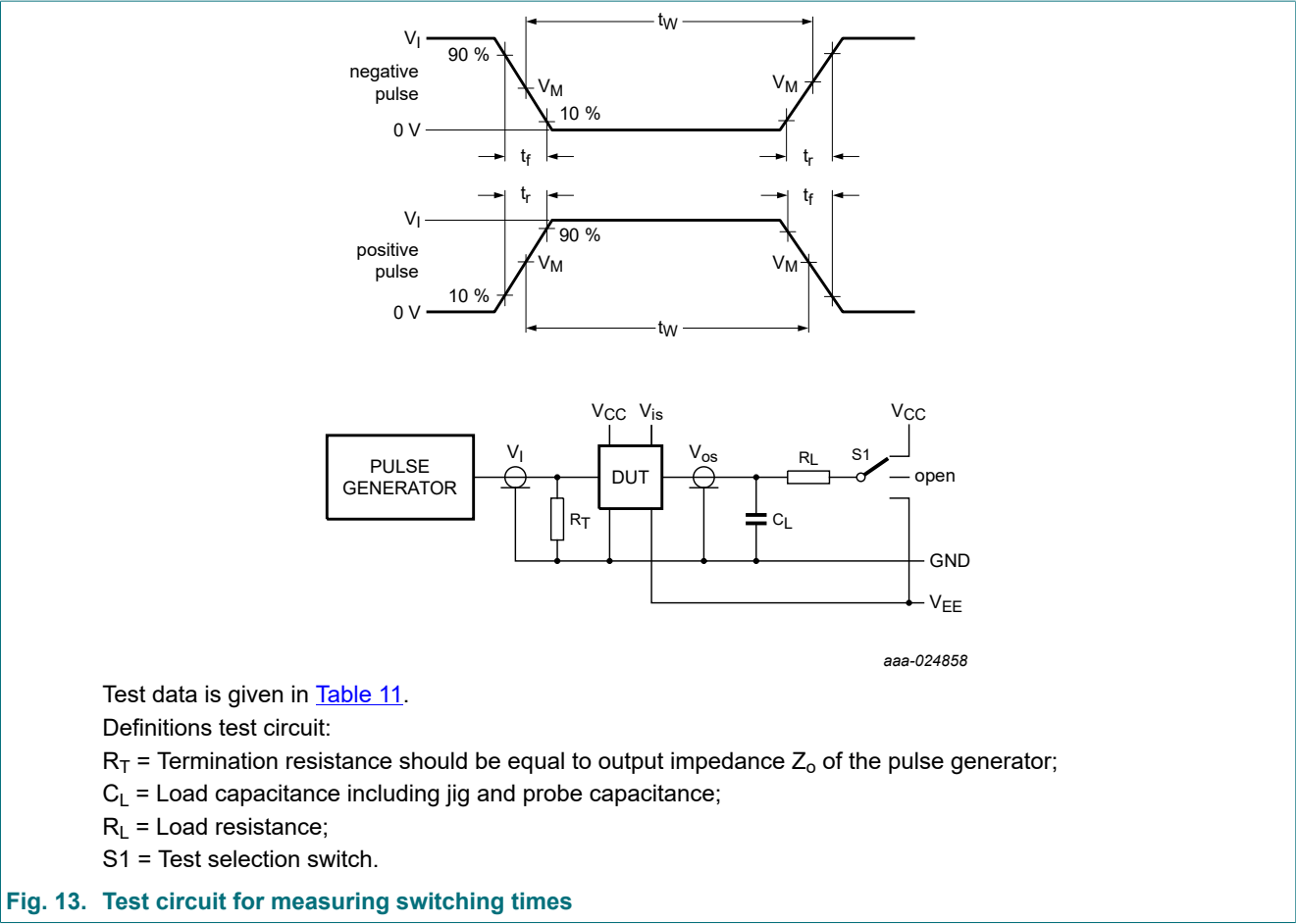


Fig. 13. Test circuit for measuring switching times

Table 11. Test data

Test	Input					Output		S1 position
	E	nS	Switch nY (nZ)	t _r , t _f		Switch nZ (nY)		
	V _I		V _{is}	at f _{max}	other [1]	C _L	R _L	
t _{PHL} , t _{PLH}	[2]		GND to V _{CC}	< 2 ns	6 ns	50 pF	-	open
t _{PHZ} , t _{PZH}	[2]		V _{CC}	< 2 ns	6 ns	50 pF, 15 pF	1 kΩ	V _{EE}
t _{PLZ} , t _{PZL}	[2]		V _{EE}	< 2 ns	6 ns	50 pF, 15 pF	1 kΩ	V _{CC}

[1] $t_r = t_f = 6$ ns; when measuring f_{max} , there is no constraint to t_r and t_f with 50 % duty factor.

[2] V_I values:
For 74HC4316: $V_I = V_{CC}$
For 74HCT4316: $V_I = 3$ V

11.2. Additional dynamic characteristics

Table 12. Additional dynamic characteristics

Recommended conditions and typical values; $GND = 0\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $C_L = 50\text{ pF}$.
 V_{is} is the input voltage at a nY or nZ terminal, whichever is assigned as an input.
 V_{os} is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
THD	total harmonic distortion	$f_i = 1\text{ kHz}$; $R_L = 10\text{ k}\Omega$; see Fig. 14				
		$V_{is} = 4.0\text{ V (p-p)}$; $V_{CC} = 2.25\text{ V}$; $V_{EE} = -2.25\text{ V}$	-	0.80	-	%
		$V_{is} = 8.0\text{ V (p-p)}$; $V_{CC} = 4.5\text{ V}$; $V_{EE} = -4.5\text{ V}$	-	0.40	-	%
		$f_i = 10\text{ kHz}$; $R_L = 10\text{ k}\Omega$; see Fig. 14				
		$V_{is} = 4.0\text{ V (p-p)}$; $V_{CC} = 2.25\text{ V}$; $V_{EE} = -2.25\text{ V}$	-	2.40	-	%
		$V_{is} = 8.0\text{ V (p-p)}$; $V_{CC} = 4.5\text{ V}$; $V_{EE} = -4.5\text{ V}$	-	1.20	-	%
$f_{(-3\text{dB})}$	-3 dB frequency response	$R_L = 50\text{ }\Omega$; $C_L = 10\text{ pF}$; see Fig. 15 [1]				
		$V_{CC} = 2.25\text{ V}$; $V_{EE} = -2.25\text{ V}$	-	150	-	MHz
		$V_{CC} = 4.5\text{ V}$; $V_{EE} = -4.5\text{ V}$	-	160	-	MHz
α_{iso}	isolation (OFF-state)	$R_L = 600\text{ }\Omega$; $f_i = 1\text{ MHz}$; see Fig. 16 [2]				
		$V_{CC} = 2.25\text{ V}$; $V_{EE} = -2.25\text{ V}$	-	-50	-	dB
		$V_{CC} = 4.5\text{ V}$; $V_{EE} = -4.5\text{ V}$	-	-50	-	dB
V_{ct}	crosstalk voltage	between digital input and switch (peak to peak value); $R_L = 600\text{ }\Omega$; $f_i = 1\text{ MHz}$; $\bar{E}$ or nS square wave between V_{CC} and GND; $t_r = t_f = 6\text{ ns}$; see Fig. 17				
		$V_{CC} = 4.5\text{ V}$; $V_{EE} = 0\text{ V}$	-	110	-	mV
		$V_{CC} = 4.5\text{ V}$; $V_{EE} = -4.5\text{ V}$	-	220	-	mV
Xtalk	crosstalk	between switches; $R_L = 600\text{ }\Omega$; $f_i = 1\text{ MHz}$; see Fig. 18 [2]				
		$V_{CC} = 2.25\text{ V}$; $V_{EE} = -2.25\text{ V}$	-	-60	-	dB
		$V_{CC} = 4.5\text{ V}$; $V_{EE} = -4.5\text{ V}$	-	-60	-	dB

[1] Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).
[2] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).

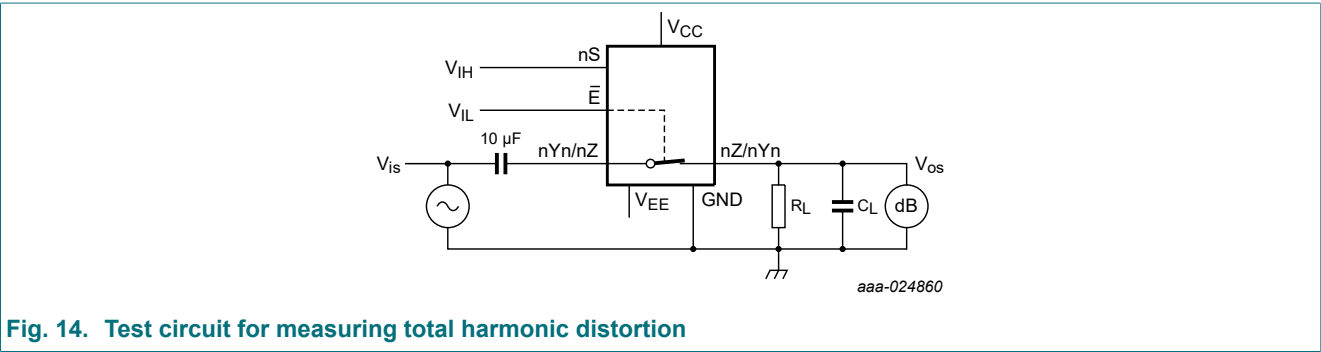
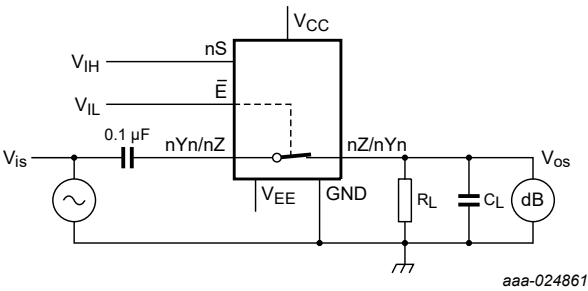
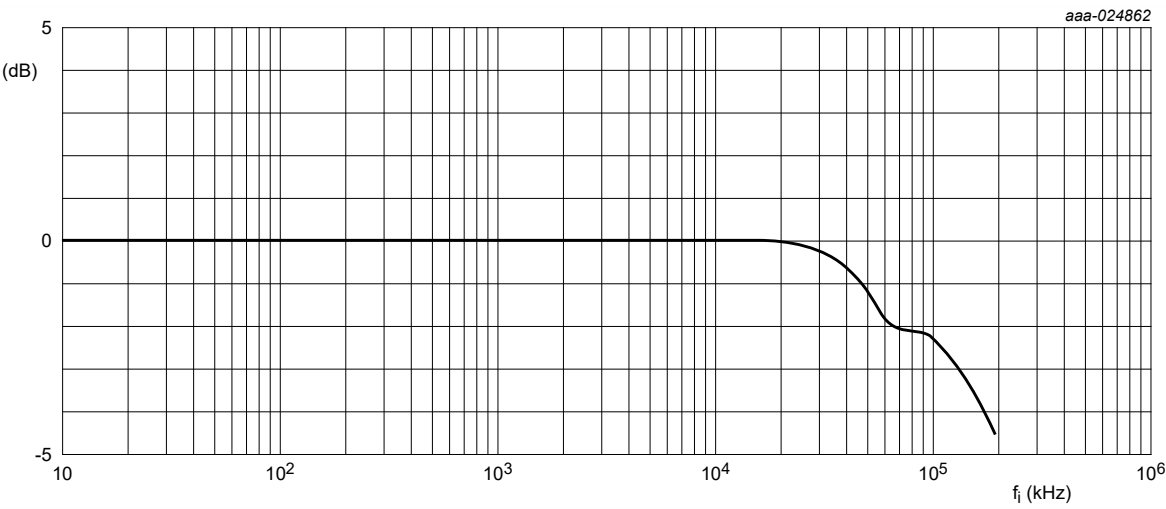


Fig. 14. Test circuit for measuring total harmonic distortion



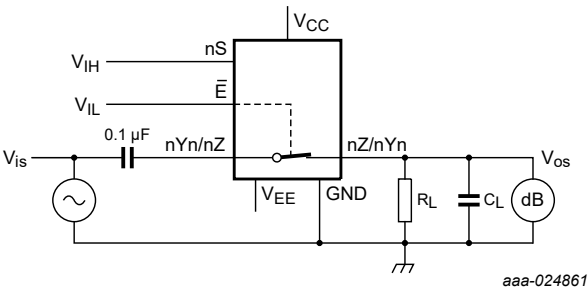
$V_{CC} = 4.5\text{ V}$; $GND = 0\text{ V}$; $V_{EE} = -4.5\text{ V}$; $R_L = 50\text{ }\Omega$; $R_S = 1\text{ k}\Omega$.

a. Test circuit



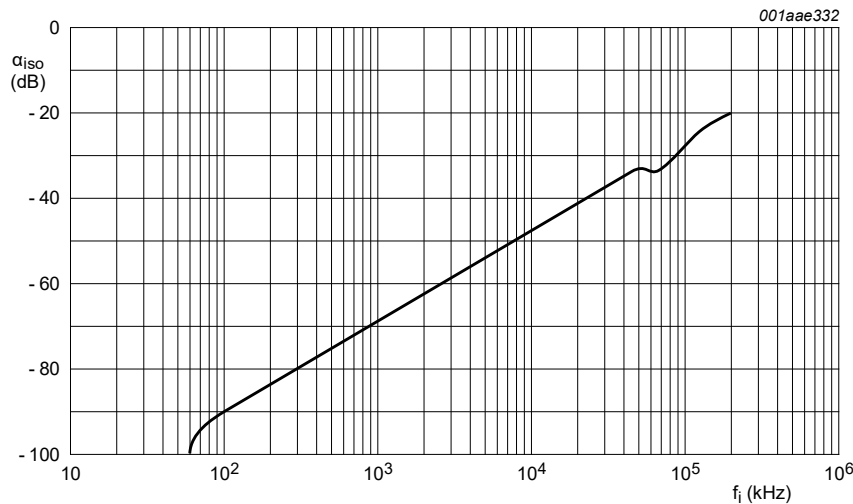
b. Typical -3 dB frequency response

Fig. 15. -3 dB frequency response



$V_{CC} = 4.5\text{ V}$; $GND = 0\text{ V}$; $V_{EE} = -4.5\text{ V}$; $R_L = 600\ \Omega$; $R_S = 1\text{ k}\Omega$.

a. Test circuit



b. Isolation (OFF-state) as a function of frequency

Fig. 16. Isolation (OFF-state) as a function of frequency

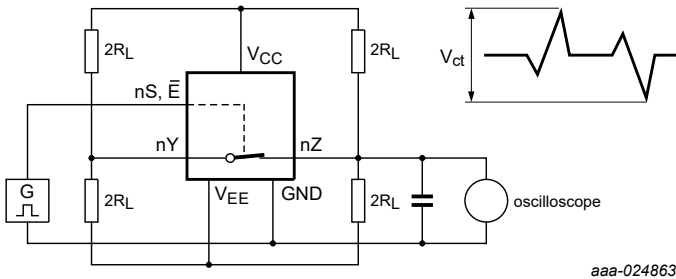


Fig. 17. Test circuit for measuring crosstalk voltage (between the digital input and the switch)

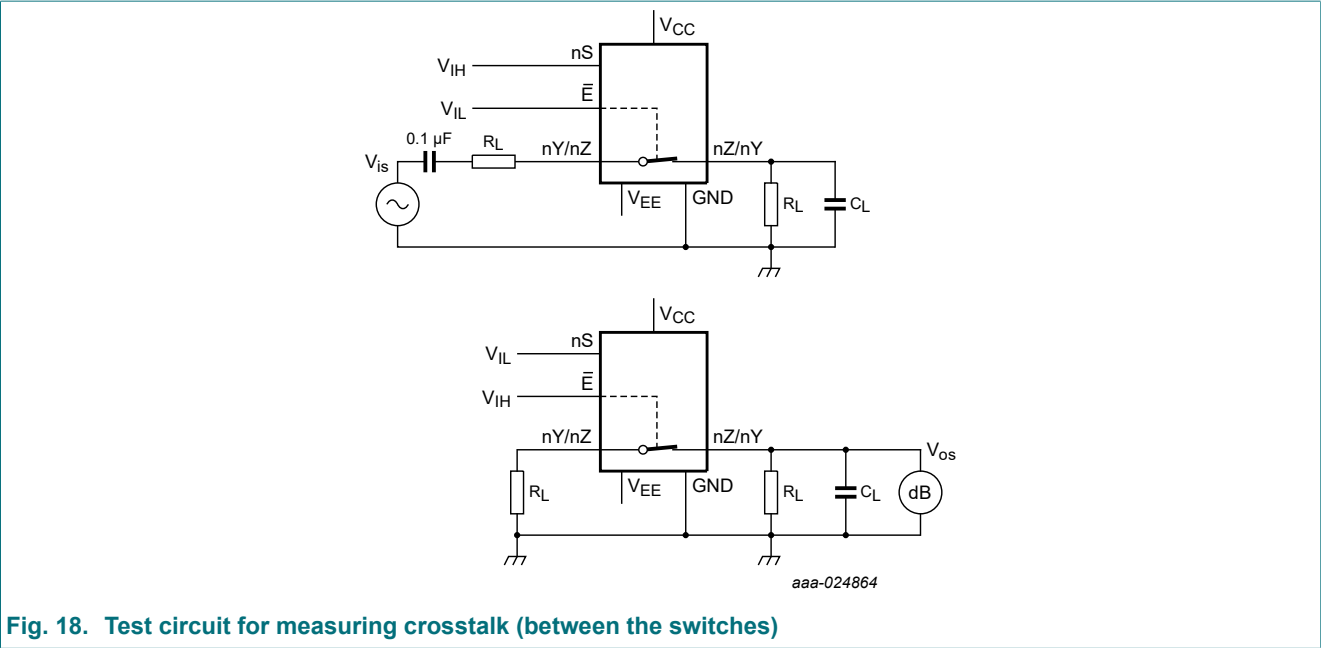


Fig. 18. Test circuit for measuring crosstalk (between the switches)

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

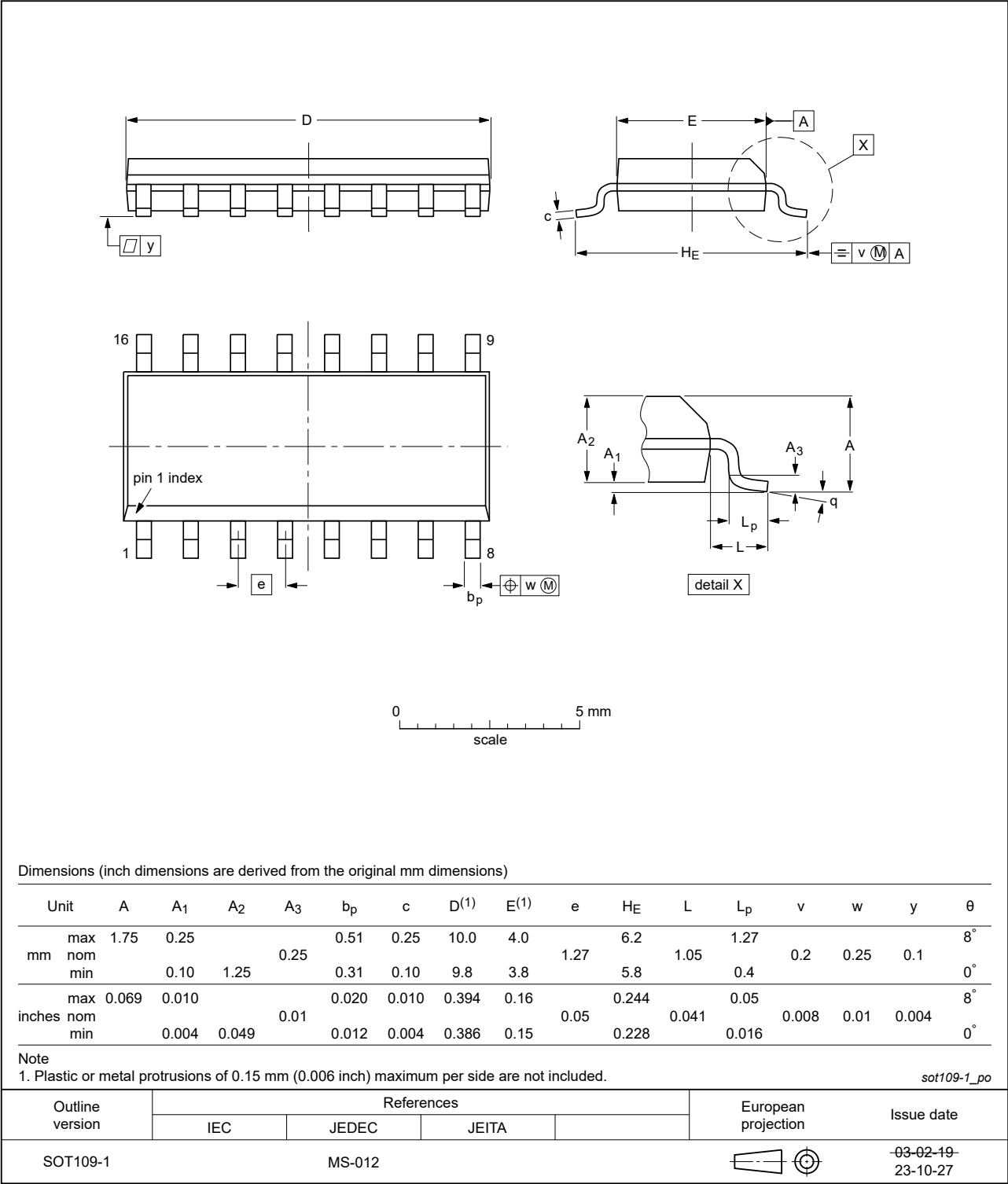


Fig. 19. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

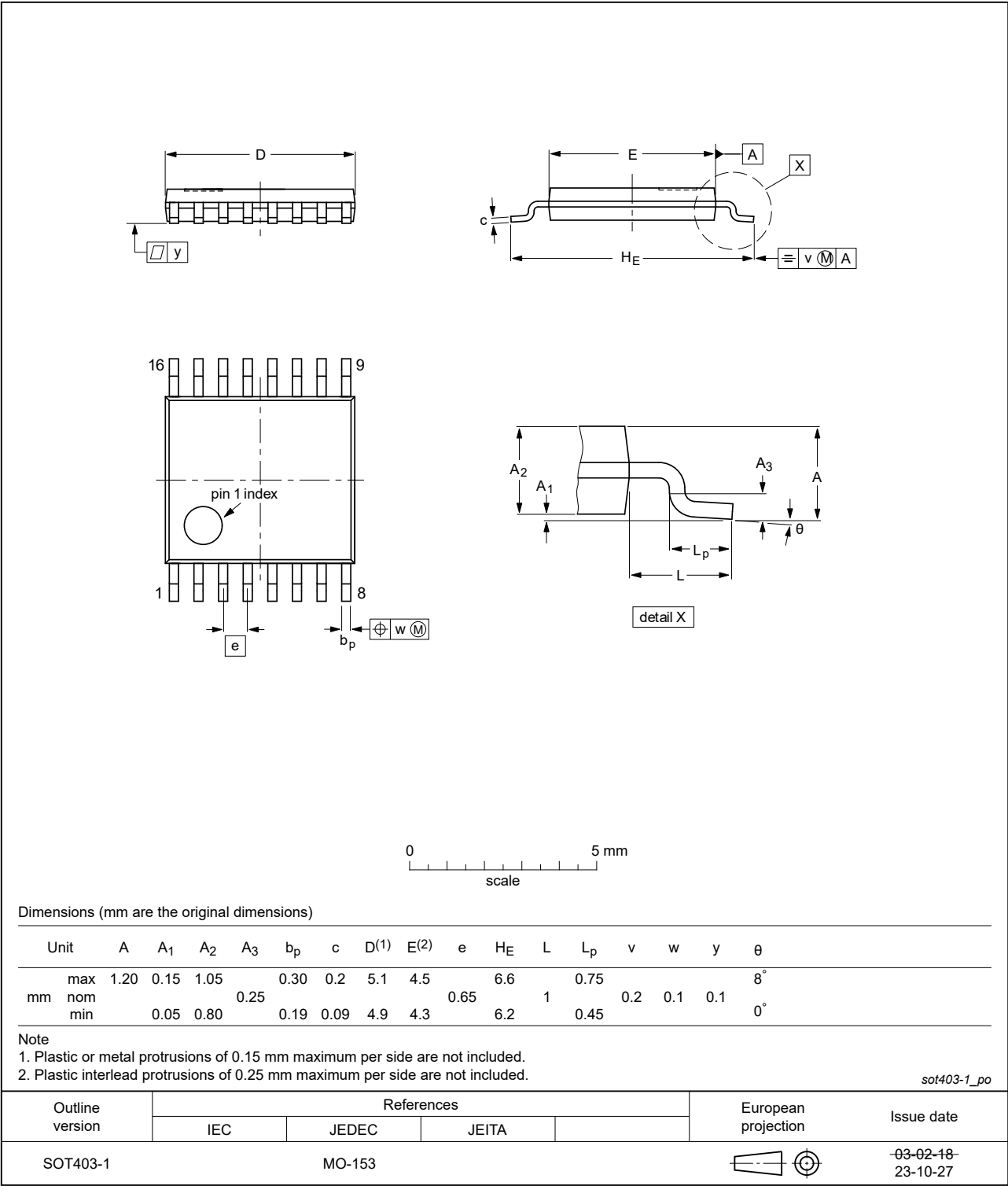


Fig. 20. Package outline SOT403-1 (TSSOP16)

13. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4316 v.7	20240326	Product data sheet	-	74HC_HCT4316 v.6.1
Modifications:	- Fig. 19, Fig. 20: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153. - Section 2: ESD specification updated according to the latest JEDEC standard.			
74HC_HCT4316 v.6.1	20231018	Product data sheet	-	74HC_HCT4316 v.5
Modifications:	- Type number 74HC4316DB (SOT338-1/SSOP16) removed. - Section 2 updated.			
74HC_HCT4316 v.5	20210310	Product data sheet	-	74HC_HCT4316 v.4
Modifications:	- Section 8: Derating values for P_{tot} total power dissipation have changed. - Type number 74HCT4316DB (SOT338-1/SSOP16) removed.			
74HC_HCT4316 v.4	20181016	Product data sheet	-	74HC_HCT4316 v.3
Modifications:	- The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. - Legal texts have been adapted to the new company name where appropriate.			
74HC_HCT4316 v.3	20170102	Product data sheet	-	74HC_HCT4316_CNV v.2
Modifications:	- The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. - Legal texts have been adapted to the new company name where appropriate. - Type numbers 74HC4316N and 74HCT4316N removed.			
74HC_HCT4316_CNV v.2	19930901	Product specification	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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